

# SANYO Semiconductors DATA SHEET

# 2SJ665 — General-Purpose Switching Device Applications

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.
- · Motor drive, DC / DC converter.
- · Avalanche resistance guarantee.

# **Specifications**

#### **Absolute Maximum Ratings** at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-27	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-108	Α
Allowable Power Dissipation	PD		1.65	W
		Tc=25°C	65	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		48	mJ
Avalanche Current *2	IAV		-27	Α

Note: \*1 V<sub>DD</sub>=30V, L=100μH, I<sub>AV</sub>=-27A

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =-1mA, V <sub>G</sub> S=0V	-100			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-100V, V <sub>GS</sub> =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> = ±16V, V <sub>DS</sub> =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-14A	15	25		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =-14A, V <sub>G</sub> S=-10V		59	77	mΩ
	R <sub>DS</sub> (on)2	I <sub>D</sub> =-14A, V <sub>GS</sub> =-4V		75	105	mΩ

Marking: J665 Continued on next page.

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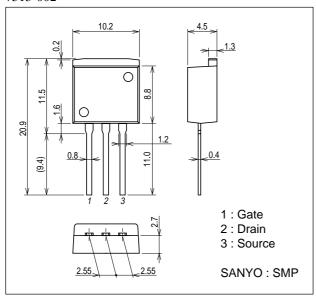
<sup>\*2</sup> L≤100μH, Single pulse

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Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V <sub>DS</sub> =-20V, f=1MHz		4200		pF
Output Capacitance	Coss	V <sub>DS</sub> =-20V, f=1MHz		280		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =-20V, f=1MHz		220		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		30		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		150		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		330		ns
Fall Time	tf	See specified Test Circuit.		135		ns
Total Gate Charge	Qg	V <sub>DS</sub> =-50V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-27A		74		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =-50V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-27A		12.8		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =-50V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-27A		14.7		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-27A, V <sub>G</sub> S=0V		-0.98	-1.2	V

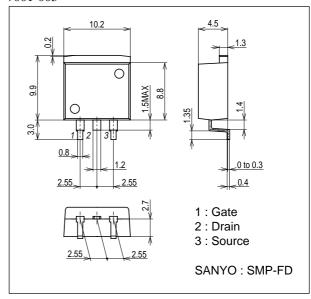
## **Package Dimensions**

unit : mm 7513-002

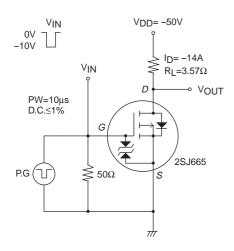


# **Package Dimensions**

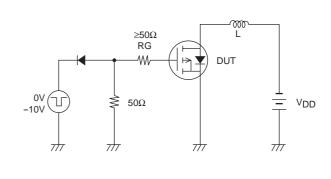
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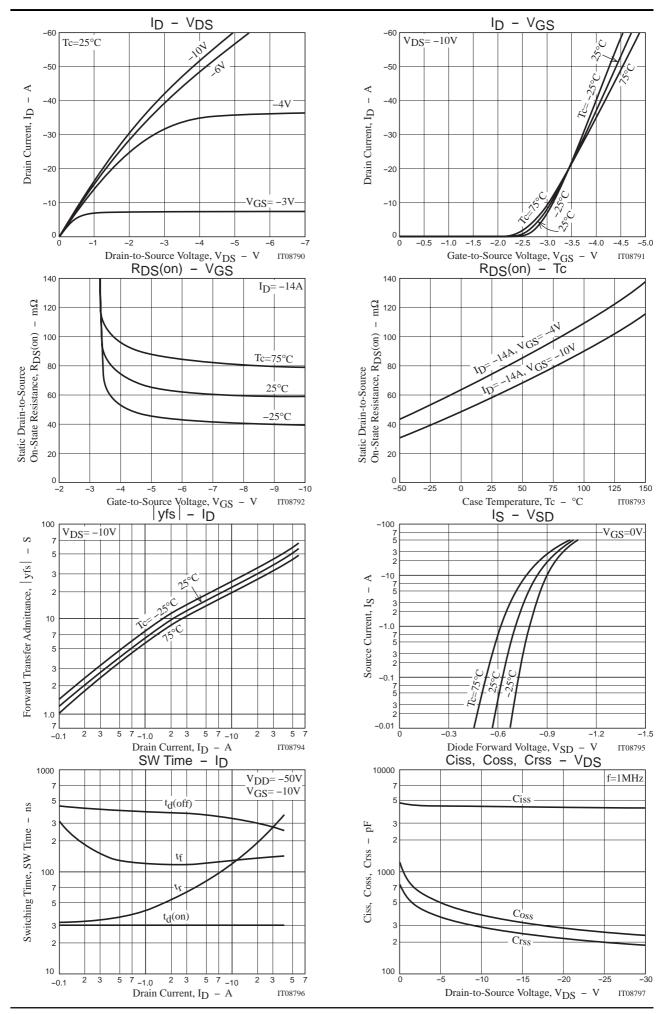


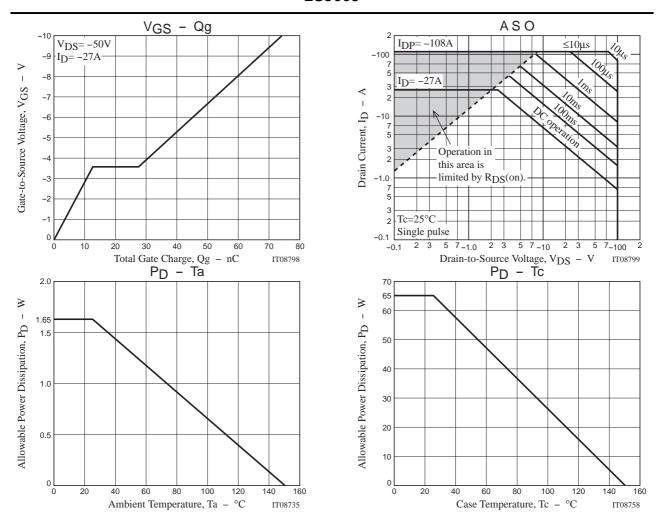
## **Switching Time Test Circuit**



# **Avalanche Resistance Test Circuit**







Note on usage: Since the 2SJ665 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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